NSN 5962-01-330-9313

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View Online at https://aerobasegroup.com/nsn/5962-01-330-9313 **Body Length:** 0.440 inches **Body Width:** Between 0.245 inches and 0.285 inches **Body Height:** Between 0.045 inches and 0.085 inches **Maximum Power Dissipation Rating:** 1.6 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 1430-01-087-6330 radar set **Features Provided:** Burn in and bipolar and monolithic and schottky and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Case Outline Source And Designator:** F-5 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:**

N/a

16 flat leads Shelf Life:

Unit Of Measure:

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Demilitarization:

No

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